

isc Silicon NPN Power Transistor

DESCRIPTION

- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 80V(Min)
- · High DC Current Gain
- · Low Saturation Voltage
- Complement to Type BD844
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

APPLICATIONS

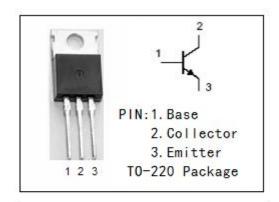
• Designed for use in television circuits and audio applications

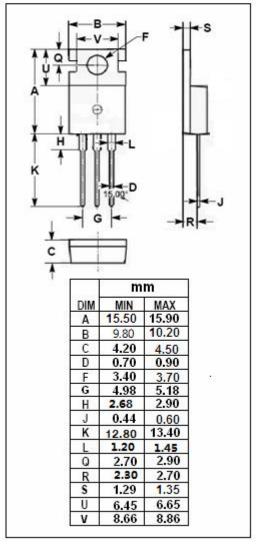
ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V_{CBO}	Collector-Base Voltage	100	V	
V _{CEO}	Collector-Emitter Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	5	V	
Ic	Collector Current-Continuous	1.5	Α	
I _{CP}	Collector Current-Peak	3.0	Α	
Pc	Collector Power Dissipation @ T _a =25°C	2	10/	
	Collector Power Dissipation @ T _C =25 ℃	10	W	
TJ	Junction Temperature	150	${\mathbb C}$	
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}\!\mathbb{C}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance,Junction to Case	12.5	°C/W
R _{th j-a}	Thermal Resistance, Junction to Ambient	62.5	°C/W







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BD843

ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Breakdown Voltage	I _C = 30mA; I _B = 0	80			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 1A; I _B = 100mA			0.8	V
V _{BE(on)}	Base-Emitter On Voltage	Ic= 1A; Vc= 2V			1.3	V
І _{СВО}	Collector Cutoff Current	V _{CB} = 30V; I _E = 0			0.1	- uA
		V _{CB} = 30V; I _E = 0; T _C = 125°C			10	
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			10	uA
h _{FE-1}	DC Current Gain	I _C = 5mA ; V _{CE} = 2V	25			
h _{FE-2}	DC Current Gain	I _C = 150mA ; V _{CE} = 2V	40		250	
h _{FE-3}	DC Current Gain	I _C = 1A; V _{CE} = 2V	25			
f⊤	Current-Gain—Bandwidth Product	I _C = 50mA ; V _{CE} = 5V		125		MHz

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